# Current-Shunt Monitor, Voltage Output, Bi-Directional Zero-Drift

The NCS199A1, NCS199A2 and NCS199A3 are voltage output current shunt monitors that can measure voltage across shunts at common-mode voltages from -0.3 V to 26 V, independent of supply voltage. Three fixed gains are available: 50 V/V, 100 V/V or 200 V/V. The low offset of the zero-drift architecture enables current sensing with maximum drops across the shunt as low as 10 mV full-scale.

The devices can operate from a single +2.7 V to +26 V power supply, drawing a maximum of 100  $\mu$ A of supply current. All versions are specified over the extended operating temperature range (-40°C to +125°C).

## Features

- Wide Common–Mode Input Range –0.3 V to 26 V
- Supply Voltage Range from 2.7 V to 26 V
- Low Offset Voltage ±150 μV Max
- Low Offset Drift (0.5  $\mu$ V/°C)
- Low Gain Error (max 1.5%)
- Rail-to-rail Input and Output Capability
- Low Current Consumption (typ 65 µA, 100 µA max)
- NCV Prefix for Automotive and Other Applications Requiring Unique Site Qualified and PPAP Capable
- These are Pb-free Devices

## **Typical Applications**

- Current Sensing (High–Side/Low–Side)
- Automotive
- Telecom
- Sensors

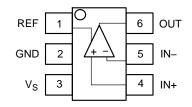


## **ON Semiconductor®**

www.onsemi.com

SC70-6 SQ SUFFIX CASE 419B

### **PIN CONNECTIONS**



## MARKING DIAGRAM



XXX = Specific Device Code (See page 4)

- M = Date Code
- = Pb–Free Package

(Note: Microdot may be in either location)

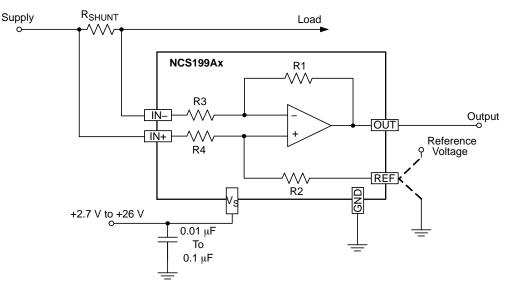
Product	Gain	R3-R4	R1-R2
NCS199A1	50	20 kΩ	1 MΩ
NCS199A2	100	10 kΩ	1 MΩ
NCS199A3	200	$5 \text{ k}\Omega$	1 MΩ

$$V_{OUT} = (I_{LOAD} \times R_{SHUNT})GAIN + V_{REF}$$

## **ORDERING INFORMATION**

See detailed ordering, marking and shipping information on page 4 of this data sheet.

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**Figure 1. Application Schematic** 

## Table 1. MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Supply Voltage (Note 1)		V <sub>S</sub>	+26	V
Analog Inputs	Differential (V <sub>IN+</sub> )–(V <sub>IN-</sub> )	V <sub>IN+</sub> ,V <sub>IN-</sub>	-26 to +26	V
	Common–Mode (Note 2)		GND-0.3 to +26	7
REF Input		V <sub>REF</sub>	GND–0.3 to ( $\mathrm{V}_{\mathrm{S}}\mathrm{)}$ +0.3	V
Output (Note 2)		V <sub>OUT</sub>	GND–0.3 to ( $\mathrm{V_{S}}\mathrm{)}$ +0.3	V
Input Current into Any Pin (N	lote 2)		5	mA
Maximum Junction Temperature		T <sub>J(max)</sub>	+150	°C
Storage Temperature Range		TSTG	-65 to +150	°C
ESD Capability, Human Body Model (Note 3)		HBM	±3000	V
ESD Capability, Machine Model (Note 3)		MM	±100	V
Charged Device Model (Note	e 3)	CDM	±1000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for safe operating parameters.

2. Input voltage at any pin may exceed the voltage shown if current at that pin is limited to 5 mA.

3. This device series incorporates ESD protection and is tested by the following methods

ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)

ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)

ESD Charged Device Model tested per AEC–Q100–011.

Latchup Current Maximum Rating: 50 mA per JEDEC standard: JESD78

## Table 2. THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics, SC70 (Note 4) Thermal Resistance, Junction-to-Air (Note 5)	$R_{\thetaJA}$	250	°C/W

 Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for safe operating parameters.

5. Values based on copper area of 645 mm<sup>2</sup> (or 1 in<sup>2</sup>) of 1 oz copper thickness and FR4 PCB substrate.

## Table 3. RECOMMENDED OPERATING RANGES

Rating	Symbol	Min	Max	Unit
Supply Voltage	V <sub>S</sub>	2.7	26	V
Ambient Temperature	T <sub>A</sub>	-40	125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## **Table 4. ELECTRICAL CHARACTERISTICS**

**Boldface** limits apply over the specified temperature range,  $T_A = -40^{\circ}C$  to  $125^{\circ}C$ , guaranteed by characterization and/or design. At  $T_A = +25^{\circ}C$ ,  $V_{SENSE} = V_{IN+} - V_{IN-}$ , and  $V_{REF} = V_S/2$ , unless otherwise noted.

#### Parameter **Test Conditions** Symbol Min Max Unit Тур GAIN NCS199A1 G 50 V/V NCS199A2 100 NCS199A3 200 Gain Error $V_{SENSE} = -5 \text{ mV}$ to 5 mV Ge ±0.2 ±1.5 % Gain Error vs. Temperature $T_A = -10^{\circ}C$ to $125^{\circ}C$ 7 20 ppm/°C ±0.01 % Nonlinearity Error $V_{SENSE} = -5 \text{ mV}$ to 5 mV Maximum Capacitive Load No sustained oscillation 1 nF **VOLTAGE OFFSET**

Offset Vo	ltage (RTI Note 6)	V <sub>SENSE</sub> = 0 mV	V <sub>OS</sub>	±5.0	±150	μV
Offset Dr	ift NCS199A2, NCS199A3 NCS199A1		δV/δΤ	0.1 0.5	0.6 2.0	μV/°C

### INPUT

Input Bias Current		V <sub>SENSE</sub> = 0 mV	I <sub>IB</sub>			60	μΑ
Common-Mode Ir	nput Voltage Range		V <sub>CM</sub>	-0.3		26	V
Common–Mode Rejection Ratio	J , 114		100	115		dB	
		V <sub>S</sub> = 3.3 V, V <sub>IN+</sub> = 3 V to +26 V, V <sub>SENSE</sub> = 0 mV		100	115		dB
		$V_{S} = 3.3 \text{ V}, V_{IN+} = 0 \text{ V to } +26 \text{ V}, V_{SENSE} = 0 \text{ mV} (T_{A} = -10^{\circ}\text{C to } 85^{\circ}\text{C})$		100	120		dB
Common–Mode Rejection Ratio	NCS199A1	V <sub>S</sub> = 5 V, V <sub>IN+</sub> = 2 V to +26 V, V <sub>SENSE</sub> = 0 mV	CMRR	97	110		dB
		$V_{S}$ = 3.3 V, $V_{IN+}$ = 3 V to +26 V, $V_{SENSE}$ = 0 mV		97	110		dB
		$V_{S} = 3.3 \text{ V}, V_{IN+} = 0 \text{ V to } +26 \text{ V},$ $V_{SENSE} = 0 \text{ mV} (T_{A} = -10^{\circ}\text{C to } 85^{\circ}\text{C})$		97	115		dB

## OUTPUT

Output Voltage Low	Referenced from GND R <sub>L</sub> = 10 kΩ to Ground	V <sub>OL</sub>	5	50	mV
Output Voltage High	Referenced from V <sub>S</sub> R <sub>L</sub> = 10 k $\Omega$ to Ground	V <sub>OH</sub>	0.05	0.2	V

## DYNAMIC PERFORMANCE

Bandwidth (f <sub>-3dB</sub> )	C <sub>LOAD</sub> = 10 pF, NCS199A1 C <sub>LOAD</sub> = 10 pF, NCS199A2 C <sub>LOAD</sub> = 10 pF, NCS199A3	BW	100 60 40		kHz
Slew Rate		SR		0.4	V/μs

### NOISE

 Spectral Density, 1 kHz (RTI Note 6)
 en
 35
 nV//Hz

## POWER SUPPLY

Operating Voltage Range	V <sub>SENSE</sub> = 0 mV	Vs	2.7		26	V
Quiescent Current	V <sub>SENSE</sub> = 0 mV	I <sub>DD</sub>		65	100	μΑ
Quiescent Current over Temperature	V <sub>SENSE</sub> = 0 mV				115	μΑ
Power Supply Rejection Ratio	$V_{S}$ = +2.7 V to +26 V, $V_{IN+}$ =18 V, $V_{SENSE}$ = 0 mV	PSRR		±0.1	±10	μV/V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

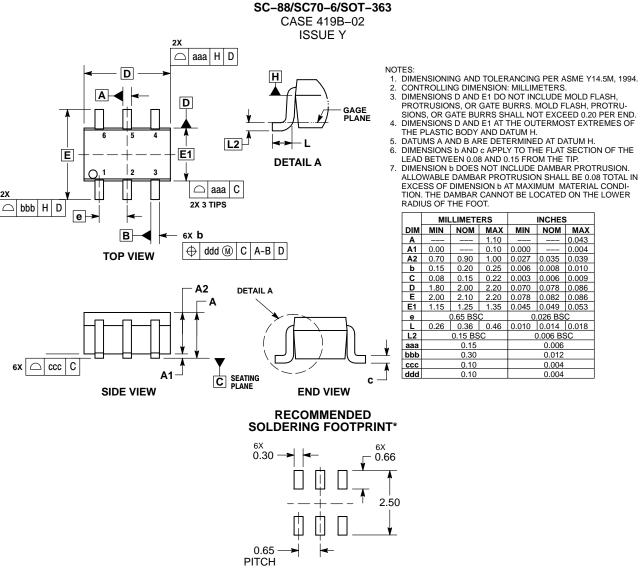
6. RTI = referenced-to-input.

## **ORDERING INFORMATION**

Device	Gain	Marking	Package	Shipping <sup>†</sup>
NCS199A1SQT2G	50	ACQ		
NCS199A2SQT2G	100	ACR	SC70–6 (Pb–Free)	3000 / Tape and Reel
NCS199A3SQT2G	200	ACP	(	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

## PACKAGE DIMENSIONS



DIMENSIONS: MILLIMETERS

MILLIMETERS

MIN NOM MAX

2.00

0.65 BSC

0.15 BSC

0.15

0.30

0.10

0.10

0.00

0.70

0.15

0.08

1.80

0.26

1.10

0.10

2.20 0.070

2.002.102.200.0780.0820.0861.151.251.350.0450.0490.053

0.90 1.00

0.36 0.46

0.000

0.20 0.25 0.006 0.008 0.010

0.15 0.22 0.003 0.006 0.009

0.027 0.035

INCHES MIN NOM MAX

0.078

0.026 BS

0.010 0.014 0.018

0.006 BSC

0.006

0.012

0.004

0.004

0.043 0.004

0.039

0.086

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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